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The CMS MTD Endcap Timing Layer: Precision Timing with Low Gain Avalanche Detectors

Marco Ferrero
on behalf of the CMS ETL GROUP



The 30th International Workshop on Vertex Detectors

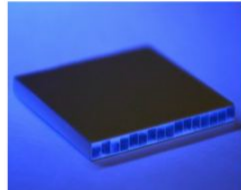
Outlook

- The CMS **MIP Timing Detector (MTD)**
- The CMS **Endcap Timing Layer (ETL)**
- ETL Sensors
 - Sensors technology and prototype
 - Laboratory measurements
 - Beam test results
- The **ETL read-out ASIC (ETROC)**
 - ETROC0 and 1, specification and beam test results

CMS MIP Timing Detector (MTD)

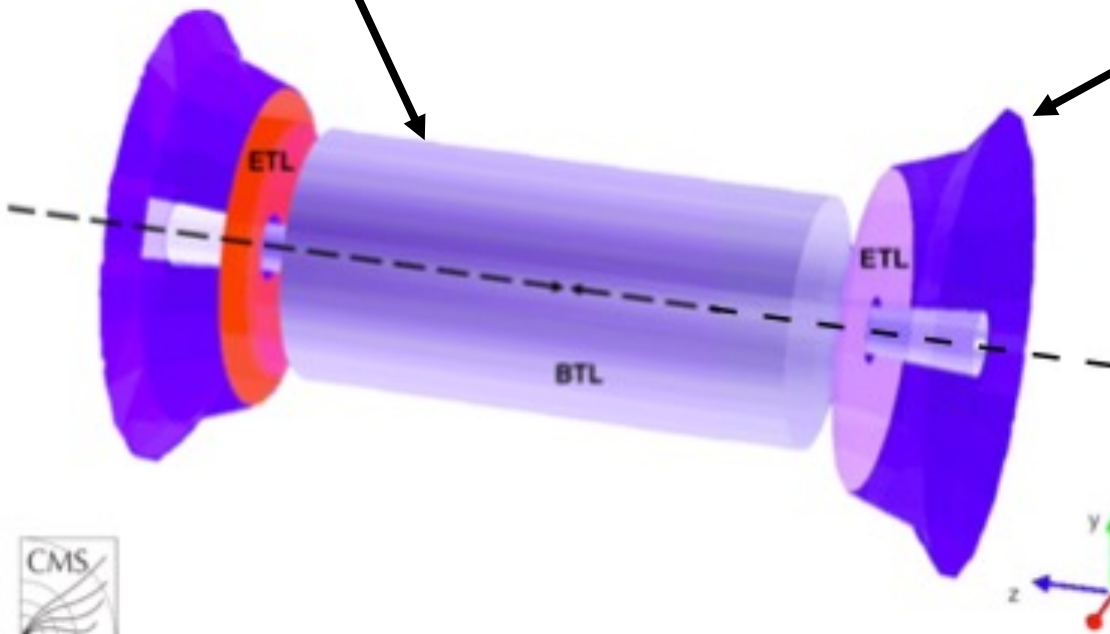
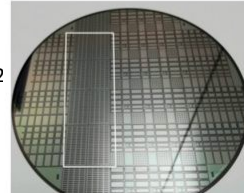
Barrel Timing Layer (BTL):

- LYSO Crystals + SiPM read-out
- $|\eta| < 1.45$
- Total surface of $\sim 38 \text{ m}^2$
- Fluence at 3 ab^{-1} : $2 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$



Endcap Timing Layer (ETL):

- Low Gain Avalanche Diodes (LGADs) with ASIC readout
- $1.6 < |\eta| < 3.0$
- Total surface of $\sim 14 \text{ m}^2$
- Fluence at 3 ab^{-1} : up to $1.7 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



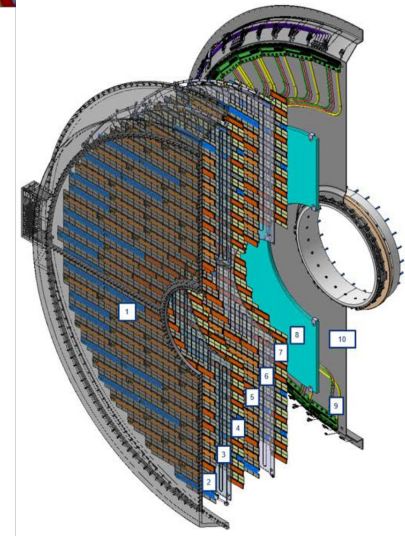
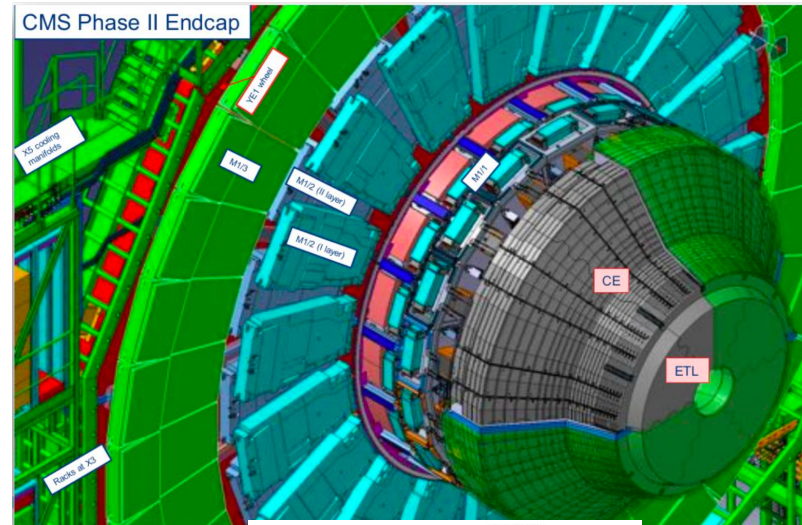
MTD will improve reconstruction by:

- Combining tracking with timing of charged particles
- Providing a **timing resolution of $\sim 30 - 40 \text{ ps}$** at the start of HL-LHC, barrel degrades to $50 - 60 \text{ ps}$ at the end of HL-LHC



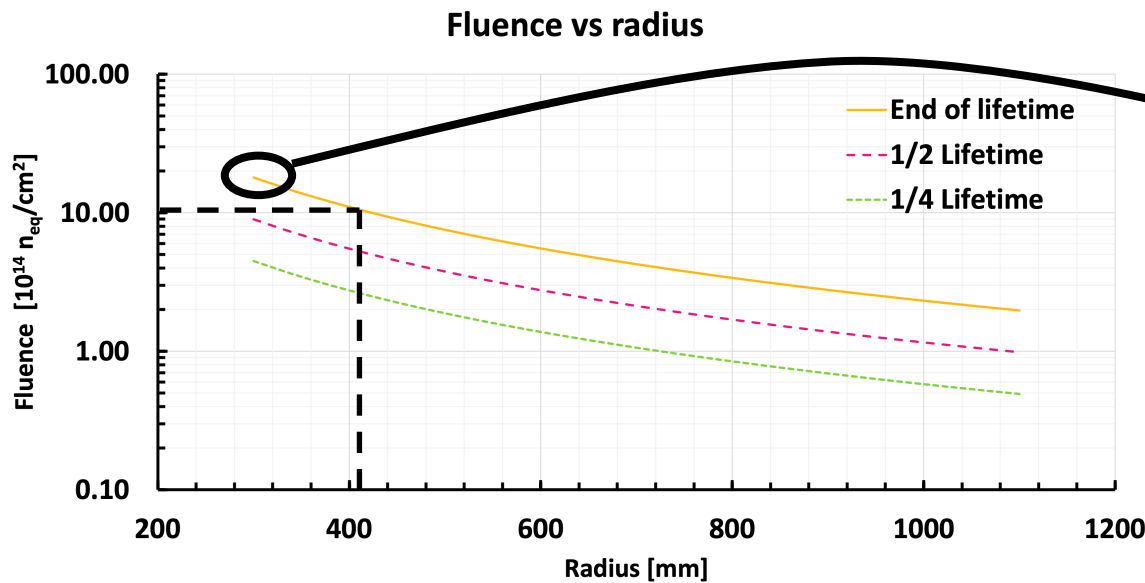
CMS Endcap Timing Layer (ETL)

- ETL will be mounted on the HGCAL nose
- **Two double-sided disks** for each endcap
 - Large geometrical acceptance (85%/disk)
 - Ensure two hits for each track
 - **Single hit resolution < 50 ps**
 - **Track resolution < 35 ps**
- Coverage:
 - $z = 3\text{ m}$ from the pp interaction
 - $1.6 < |\eta| < 3.0$
 - $0.31\text{ m} < \text{Disk Radius} < 1.2\text{ m}$



CMS Endcap Timing Layer - radiation environment

ETL will operate in a large range of radiation fluences
ETL must ensure unchanged performances up to the end of lifetime



In the inner region ($|\eta| = 3.0$)

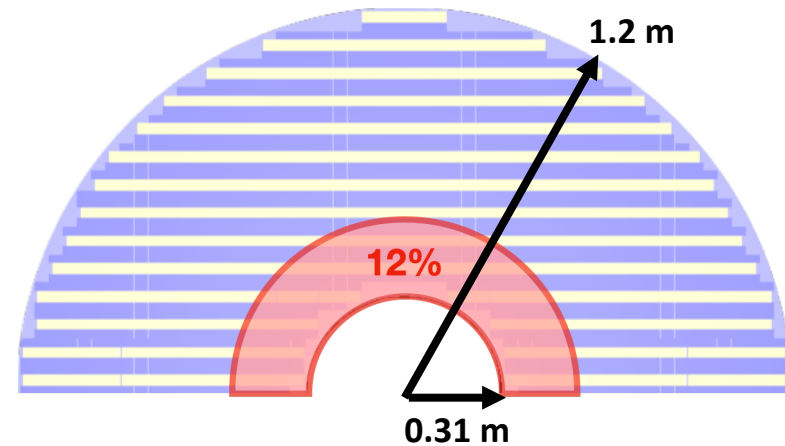
1.7×10^{15} n_{eq}/cm² is the expected maximum fluence at the end of HL-LHC program

2.5×10^{15} n_{eq}/cm² is the expected maximum fluence considering a **x1.5 safe factor**

The fluence will exceed 1×10^{15} n_{eq}/cm² only on a small fraction of the detector surface, after ½ lifetime

CMS Endcap Timing Layer

- $1 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$: turning point in term of performance degradation
 - 88% of ETL $< 1 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2 \rightarrow$ performance degradation not an issue
 - Only 12% $> 1 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2 \rightarrow$ optimization sensor design to achieve unchanged performances also in this regionOperating temperature below -25°C
- **Fill-Factor** (ratio between active and total detector area) $> 95\%$
- **Low occupancy** ($< 0.1\%$ at low η , 1% at highest η) to avoid double hits and ambiguous time assignment



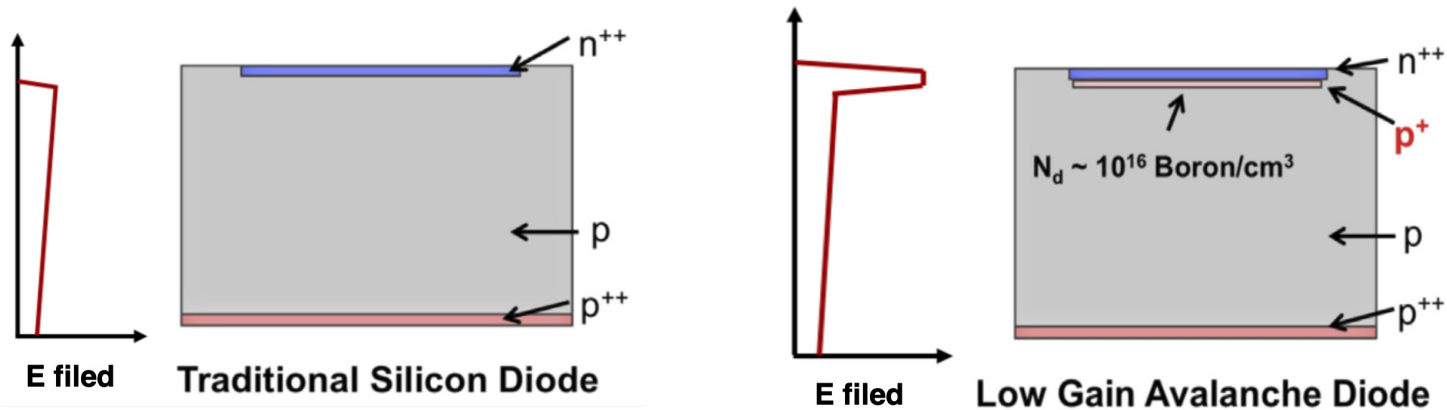
Radiation fluence expected in ETL, in red the region $> 1 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

ETL sensors technology

ELT will be instrumented with Low Gain Avalanche Diodes (LGADs) optimized (50 μ m-thick) for timing measurements

LGAD technology:

- **p⁺ gain layer** implanted underneath n⁺⁺ electrode
 - High located electric field ($E > 300$ kV/cm)
 - **charge multiplication**
 - **Moderate internal gain 10 – 30** to maximize signal/noise ratio

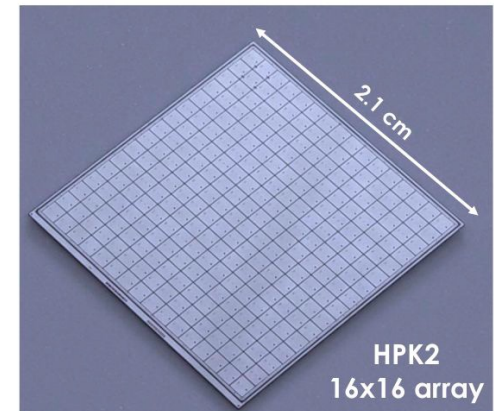


ETL sensors technology

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 - High located electric field ($E > 300$ kV/cm)
 - **charge multiplication**
 - **Moderate internal gain 10 – 30** to maximize signal/noise ratio
- **Sensor Requirements:**
 - Pad size of few mm² determined by occupancy and read-out electronics (**pad capacitance $\sim 3 - 4$ pF**)
 - Gain, leakage current and breakdown voltage uniformity
 - Low leakage current
 - Provide **large and uniform charge**, > 8 fC when new and > 5 fC at the highest irradiation fluence
 - **No-gain distance** between adjacent pads < 50 μ m
- **The final sensor :**
 - 16x16 pad array with 1.3x1.3 mm² pads



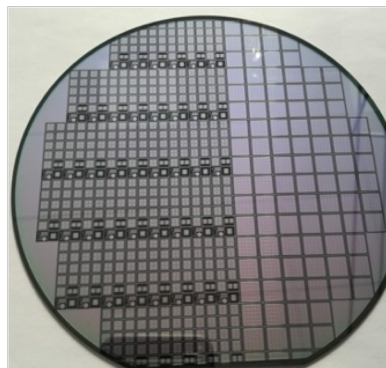
ETL sensor prototypes

Large size prototypes have been produced by FBK (Italy) and HPK (Japan)
R&D activities on ETL sensor design are on going

Latest **FBK** production:

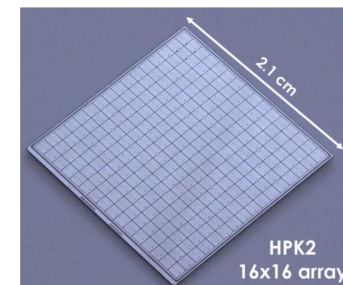
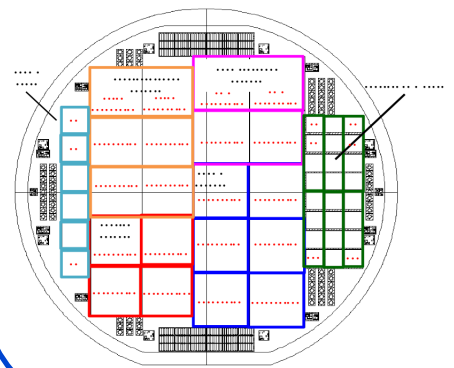
- **Gain layers** with different doses and depths of implant
- **Carbon** co-implantation into gain layer to improve the radiation resistance
- **9 inter-pad layouts**

Thickness	DEPTH	Dose Pgain	Carbon	Diffusion
45	Standard	0.98	1.*A	CH-BL
45	Standard	0.98	1.*A Spray	CH-BL
45	Standard	0.98	0.8*A	CH-BL
45	Standard	0.98	0.4*A	CH-BL
25	Standard	0.94	1.*A	CH-BL
35	Standard	0.94	1.*A	CH-BL
55	Standard	0.98	1.*A	CH-BL
45	deep	0.70	1.*A	CBL
55	deep	0.70	1.*A	CBL
45	deep	0.70	0.6*A	CBL
45	deep	0.70		BL
45	deep	0.74	1.*A	CBL
45	deep	0.74	0.6*A	CBL
45	deep	0.74	1.*A	CBH
55	deep	0.74	1.*A	CBH
45	deep	0.74	0.6*A	CBH
45	deep	0.74		BH
45	deep	0.78	A	CBH
45	deep	0.78	0.6*A	CBH



Latest **HPK** production:

- **4 gain layer** doses
- **No carbon** co-implantation
- **4 inter-pad layouts**



Laboratory measurements: Probe Station

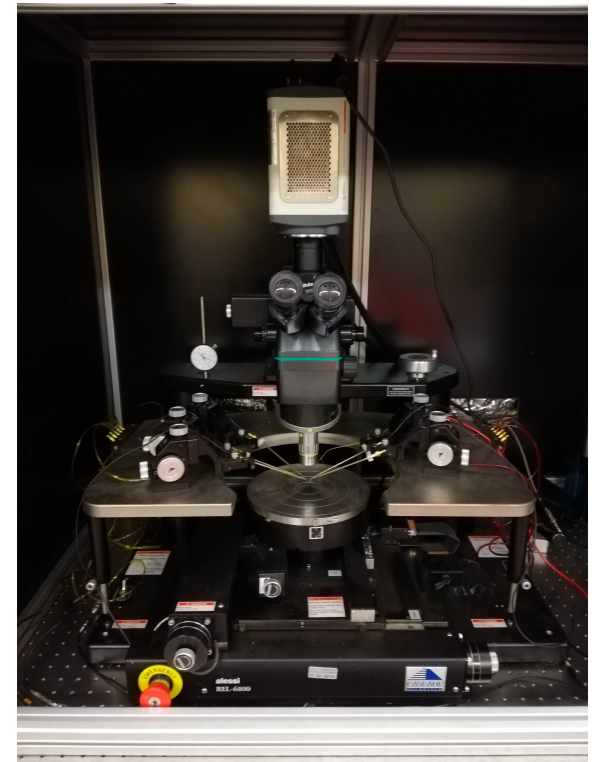
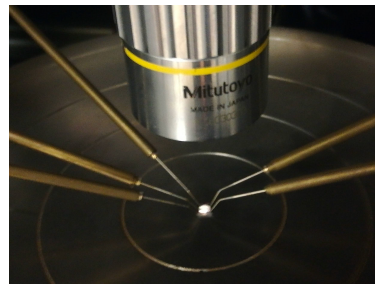
LGAD sensors are tested on wafer and after dicing with probe station

Two main tests are usually performed:

- Current vs Bias Voltage (IV Curve)
- Capacitance vs Bias Voltage (CV Curve)

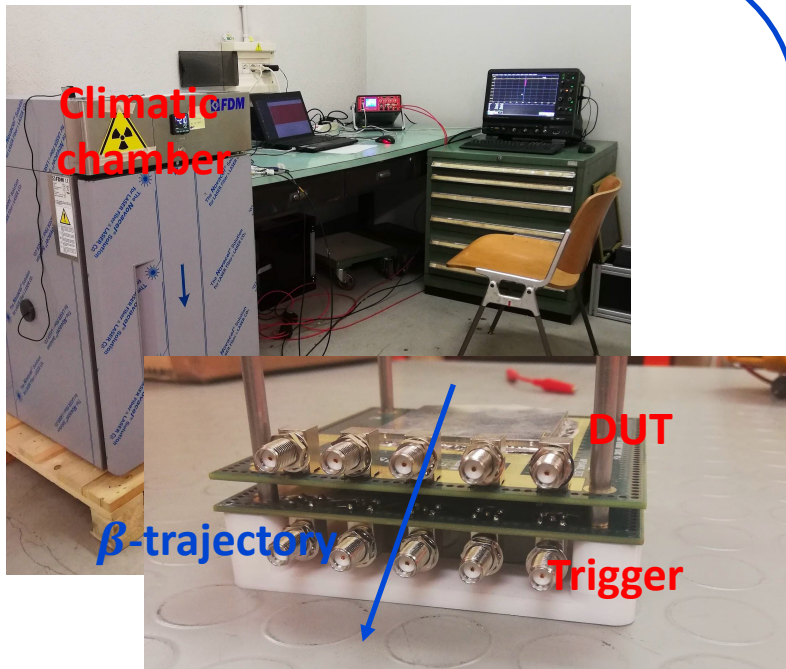
These measurements provide information on:

- Leakage current
- Breakdown voltage
- Production uniformity
- Evolution of the gain layer with radiation



Probe station in the Torino Laboratory of Innovative Silicon Sensors

Laboratory measurements: β -setups

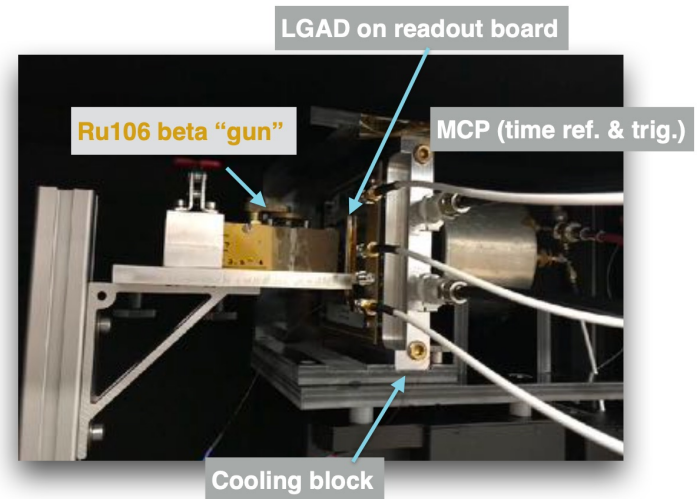


Torino:

- Sr^{90} source
- DUT + trigger in a climatic chamber
- Automated DAQ and analysis system

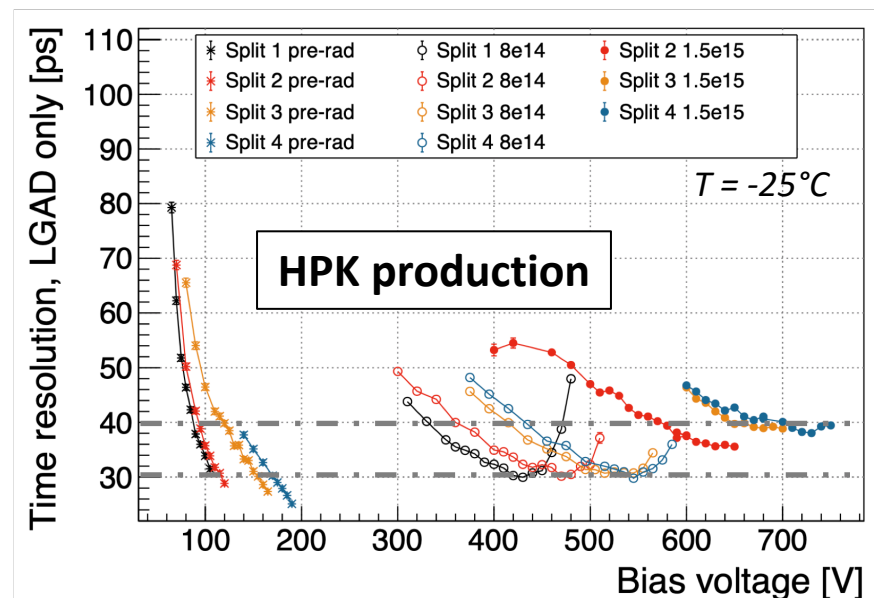
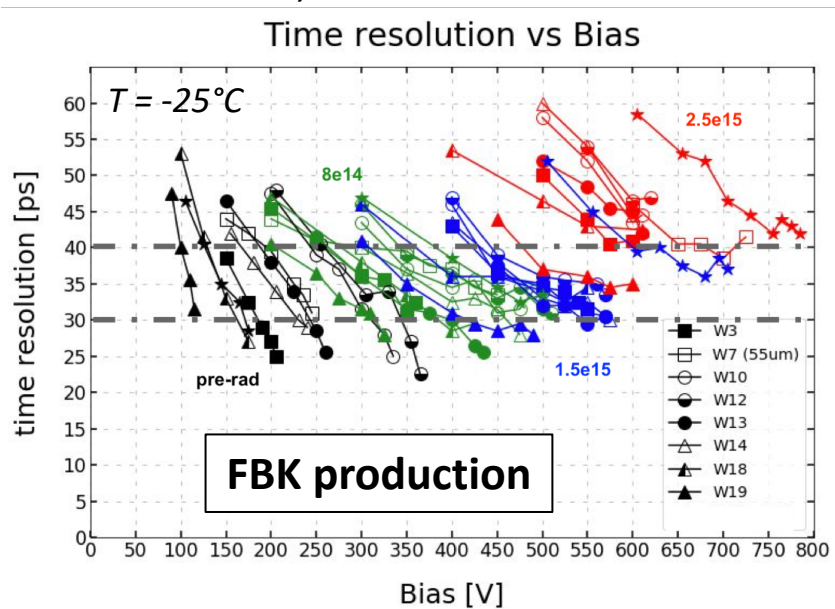
FNAL:

- In Fermilab SiDet Laboratory
- Sr^{90} source
- MCP used as time reference and trigger
- DUT mounted on a cooling block



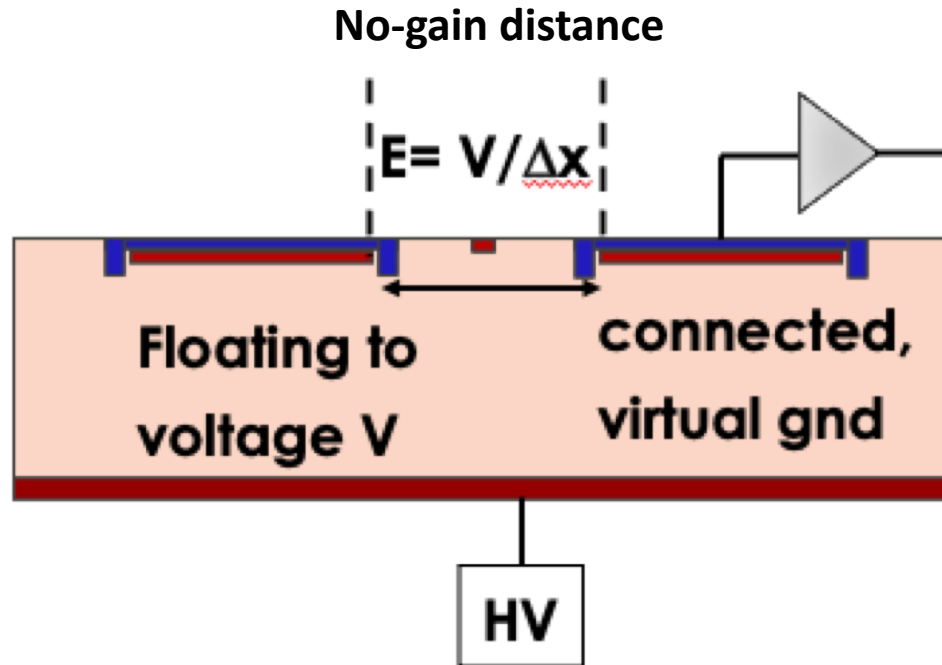
ETL sensors - Laboratory measurements: timing resolution

- Laboratory setups in Torino and Fermilab based on a Sr^{90} β -source
- Sensor performances are benchmarked using very fast **low noise electronics**
- Both FBK and HPK sensors achieve a **time resolution < 40 ps** up to $2.5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
 - With both the latest FBK and HPK production, ETL able to avoid performance degradation even in its innermost part
 - Results might change with ELT ASIC. Additional resolution contribution from ASIC, discussed later



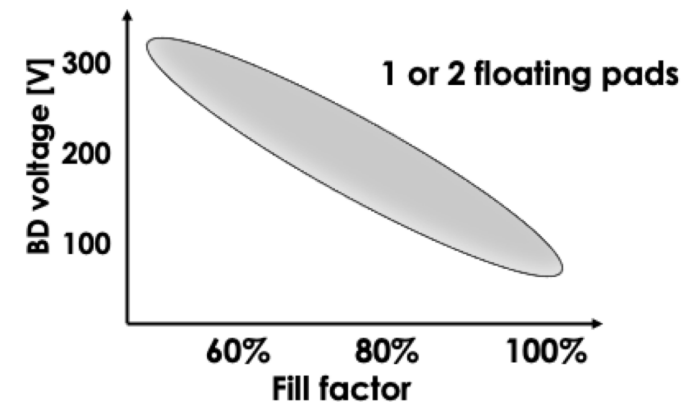
ETL sensors - no-gain distance and floating pad resiliency

Too narrow no-gain distance causes early breakdown as the floating pad resiliency get worse



No-gain distance compromise:

- Narrow enough to allow ETL reaching **95% of fill factor**
- Large enough to increase **floating pad resiliency**



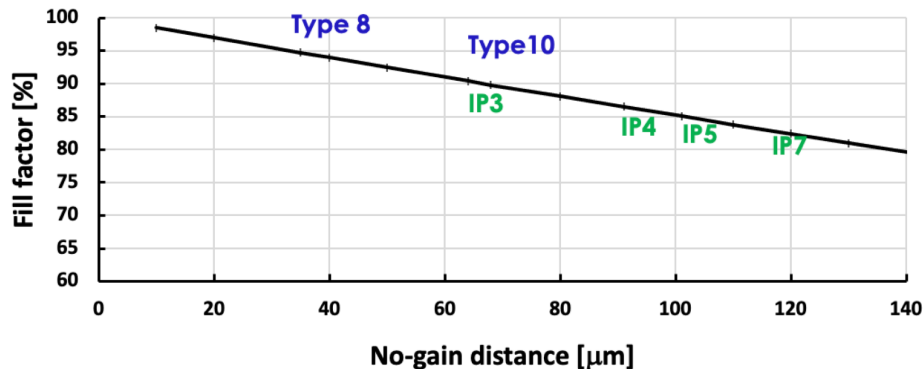
ETL sensors - Laboratory measurements: no-gain distance

No-gain distance between adjacent pads is performed with Particulars Transient Current Technique setup

	Inter-pad Type	Bias [V]	No-gain distance [μm]	Fill-Factor	
FBK	UFSD3.2	T4	230	35	94.6%
FBK	UFSD3.2	T8	230	40.5	93.9%
FBK	UFSD3.2	T10	200	68	89.8%
HPK	HPK2	IP3	220	64.2	90.4%
HPK	HPK2	IP4	220	91.1	86.5%
HPK	HPK2	IP5	220	101.8	85%
HPK	HPK2	IP7	220	124.4	82.4%

No-Gain area width and corresponding fill-factor from latest FBK and HPK production

Fill factor vs no-gain distance for a 1.3 x 1.3 mm² pad



Smaller inter-pad allows better fill-factor

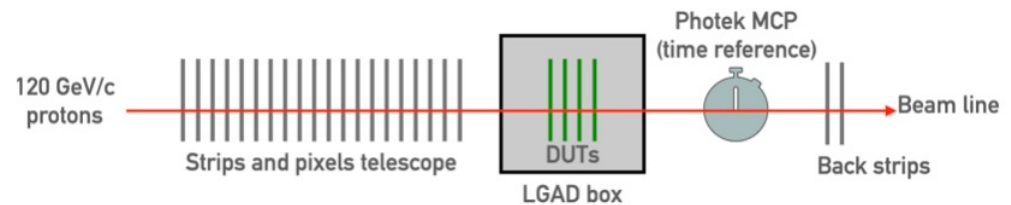
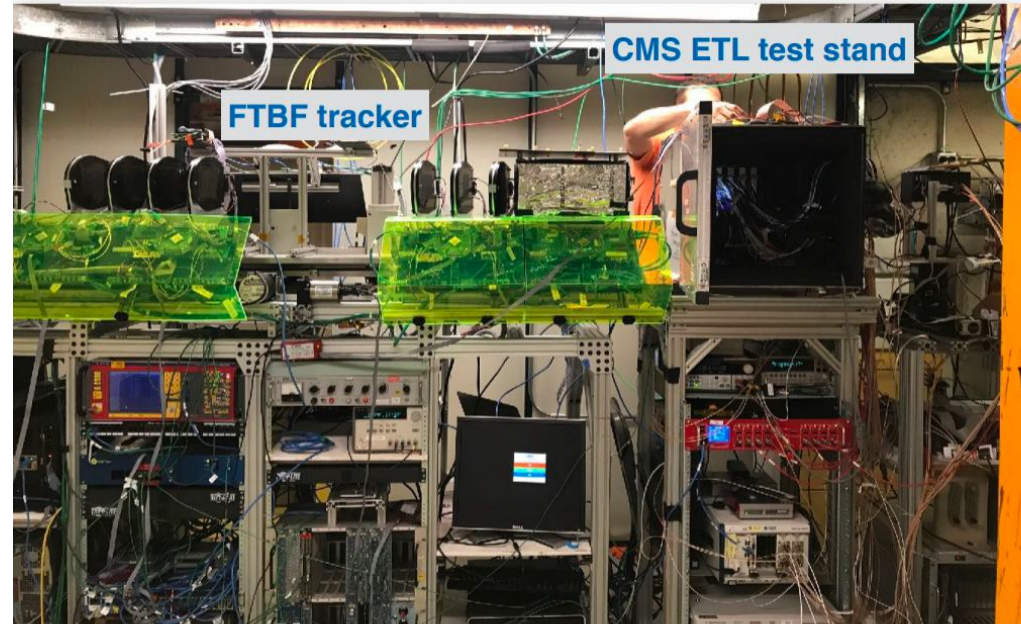
→ Study after irradiation needs to be performed

ETL sensors – Beam Test

Fermilab beam test facility:

- **120 GeV/c proton beam**
- An independent **scintillator** provides trigger
- Precise tracking performed with **pixels** and **strips telescope**
- **Cold box**
- **High-speed Photek Micro-Channel Plate** provides reference timestamp with **10 ps resolution**

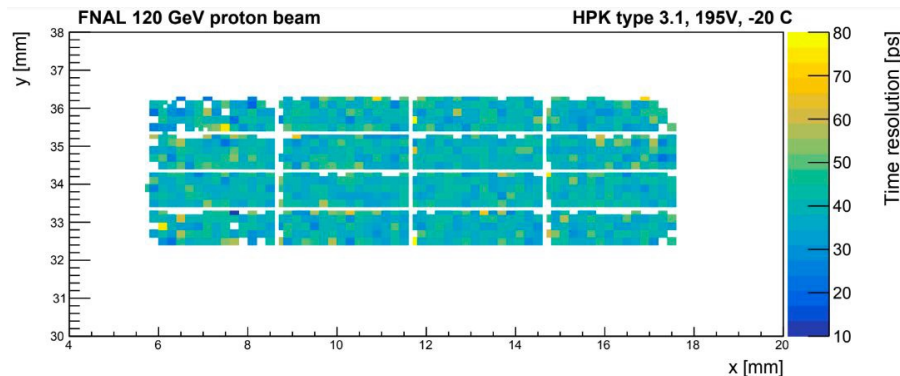
→ Study of a limited number of sensors with high precision



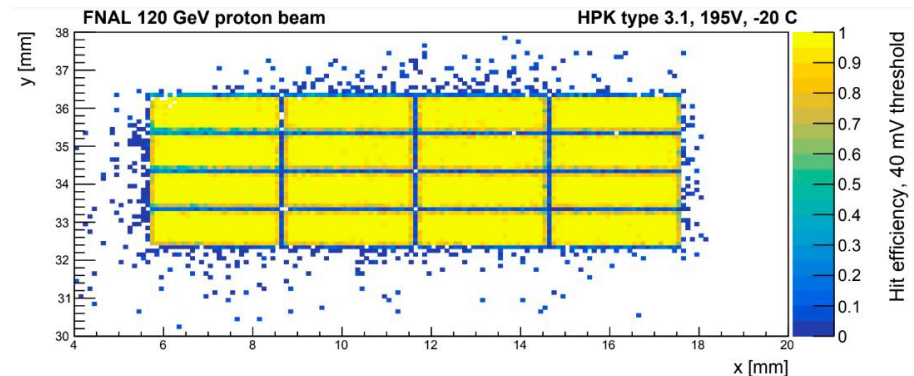
ETL sensors – Beam Test

Two results regarding a 4x4 LGAD array

Time resolution uniformity,
 $\sigma_t \sim 40$ ps all across the sensor active area



Hit efficiency uniformity $\sim 100\%$



LGAD sensors are highly uniform and efficient, able to achieve the target resolution even on large multi-pad arrays

ETL ASIC – ETROC prototypes

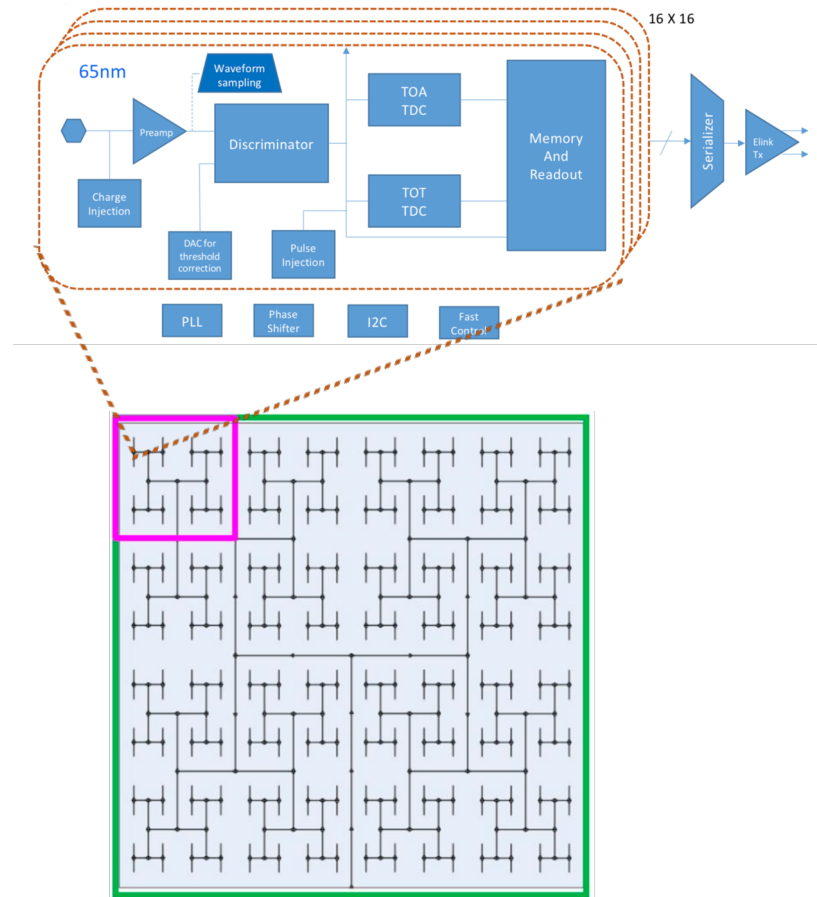
Endcap Timing Layer Read-Out Chip (ETROC) is the ETL read-out ASIC

To achieve **time resolution < 50 ps** per single hit:

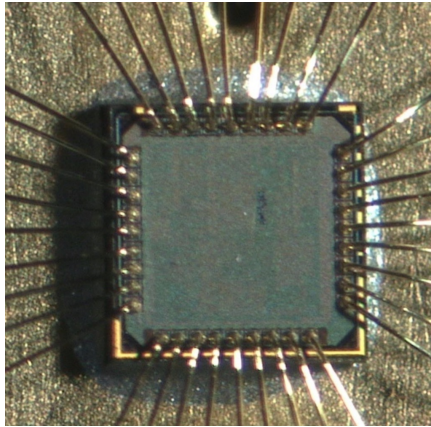
- Low noise and fast rise time
- Power budget: 1W/chip, 3mW/channel

Three prototype version before the full-size 16x16 chip:

- **ETROC0** and **ETROC1** produced and tested
 - ✓ **ETROC0**: single analog channel
 - ✓ **ETROC1**: full front-end with TDC and 4x4 clock tree
- **ETROC2** design in progress: full functionality + full size



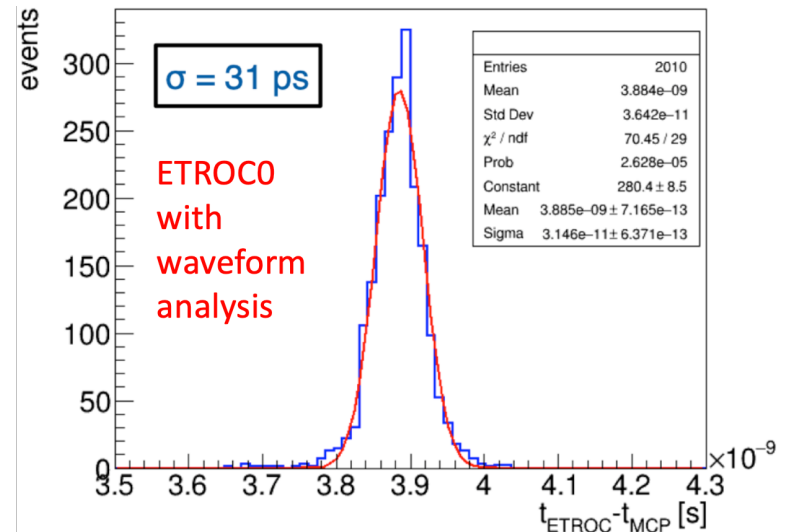
ETROCO



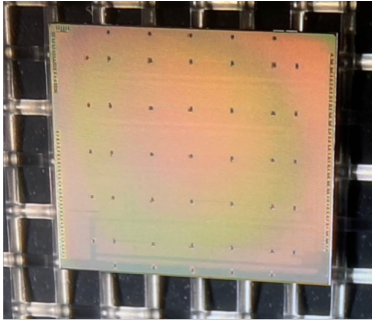
Goal: measure core front-end analog performance

- Jitter measurements agree with post layout simulation
- Power consumption for preamp and discriminator consistent with expectation
- **31 ps timing resolution** achieved at FNAL test beam with ETROCO+LGAD

Time resolution measured at FNAL beam test, using a fast MCP as reference

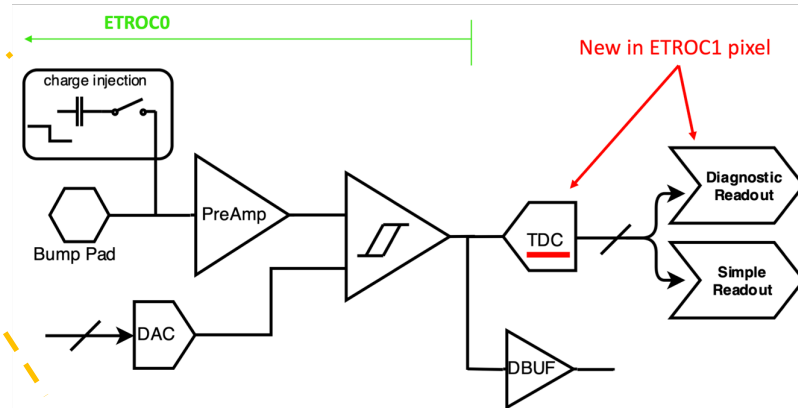
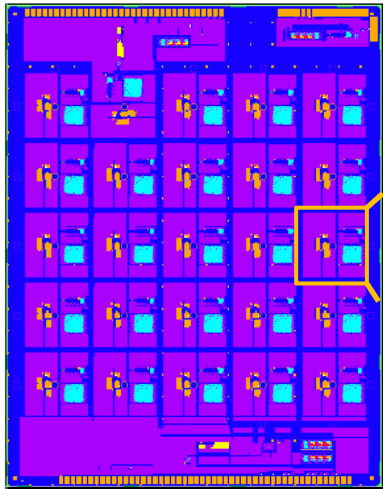


ETROC1



ETROC1 is the 2nd prototype version: 4x4 pixel + TDC

- ETROC0 front-end
- ETROC TDC: new design optimized for **low power**
- Low power achieved using simple delay cells with **self-calibration**
- Measured **TDC performance** as a **6ps contribution** to the resolution

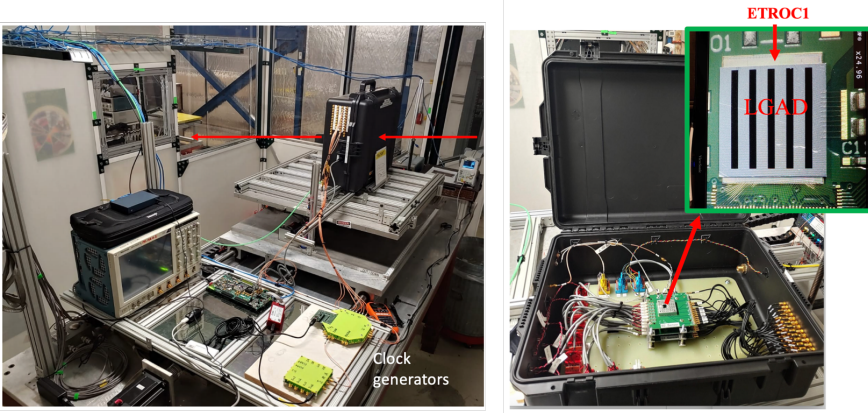


40 MHz noise observed on bump bonded ETROC1 + LGAD

- Coupled through the sensor due to 40MHz clock activity in the circular buffer memory
- The noise can be suppressed by setting the discriminator threshold to ~ 8 fC
→ under investigation

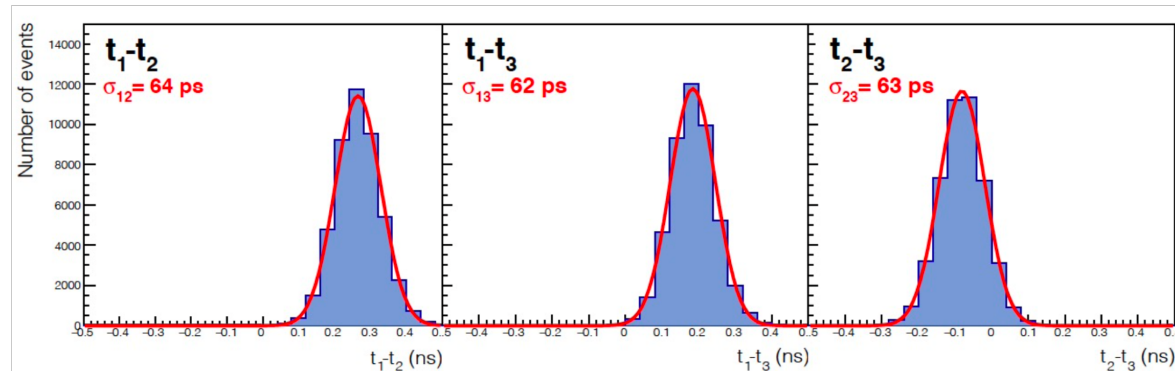
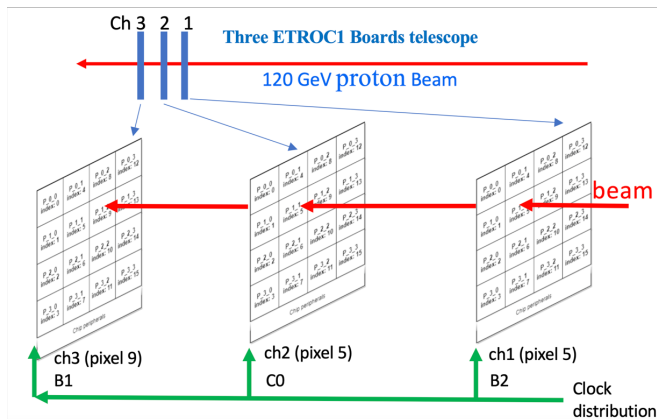
ETROC1

ETROC1 beam telescope at FNAL beam facility



From preliminary analysis of the data from ongoing beam test at FNAL, **the total time resolution per hit** for each LGAD+ETROC1 layer has reached:

$$\sigma_i = \sqrt{(\sigma_{ij}^2 + \sigma_{ik}^2 - \sigma_{jk}^2)/2} \sim \mathbf{42-46 \text{ ps}}$$



Summary

- The **CMS Endcap Timing Layer** will provide time measurements of charged particles with single-hit **time resolution < 50 ps**, helping the CMS detector to maintain its excellent performances in the very challenging environment of the HL-LHC
- ETL will be instrumented with **Low-Gain Avalanche Diodes (LGADs)** and read-out by **ETROC ASIC**
- The latest LGAD productions have been measured both in the laboratory and during beam tests, to ensure they meet all the specifications:
 - **Highly uniform sensors**: leakage current, gain and breakdown voltage
 - **Timing resolution < 40 ps** up to $2.5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
 - No-gain region width < **120 μm** in wider layout
 - Beam test results showed **100% efficiency** and **uniform time resolution** across the whole active area of large LGAD arrays
- **ETROC** is required to consume low power while providing excellent timing performances
 - **ETROC1** is the second prototype version: 4x4 pixels + low-power TDC
 - 40MHz noise** observed → can be suppressed by setting discriminator th at 8 fC
 - 42-46 ps time resolution** has been measured during beam test at FNAL
 - **ETROC2** is being designed (submission in 2022)



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Backup

Towards HL-LHC

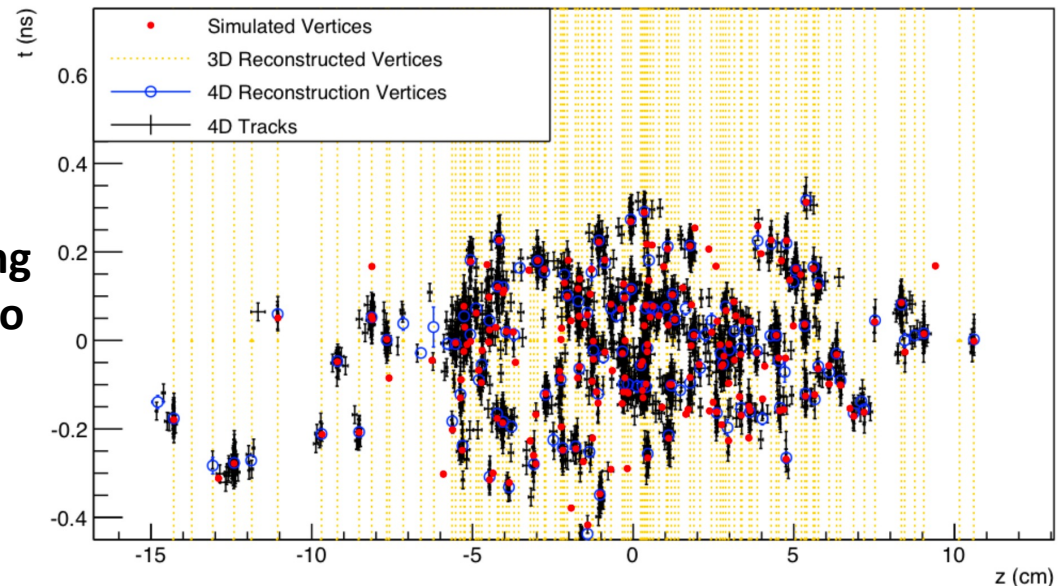
At High Luminosity LHC instantaneous luminosity will increase by a factor ~ 5

- 140-200 proton-proton collisions per bunch crossing
- Difficult in object reconstruction and particle identification due to spatial overlap of tracks

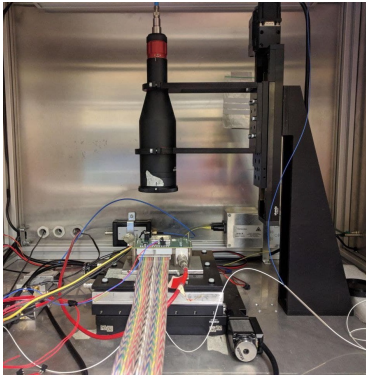
The add of timing information will help to separate overlapping events in space

- Creation of a timing detector providing 4D tracking
- A timing detector with 30-40ps of resolution will reduce the effect of high pile-up

The Minimum Ionizing Particle Timing detector (MTD) has been designed to accomplish this task



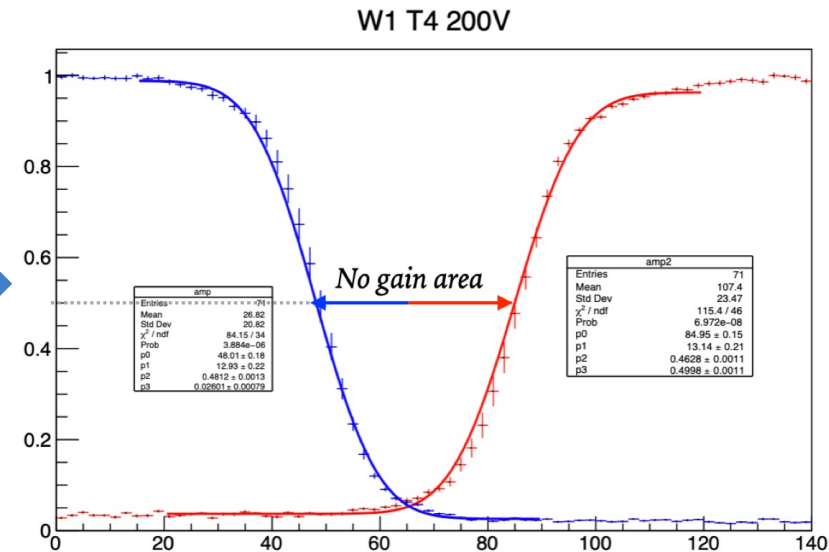
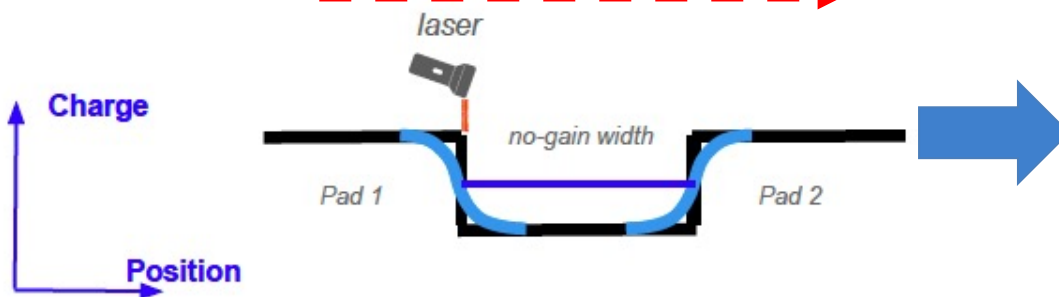
Laboratory measurements: no gain distance



No-gain distance between adjacent pads is performed with Particulars Transient Current Technique setup:

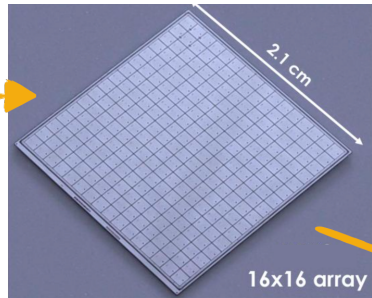
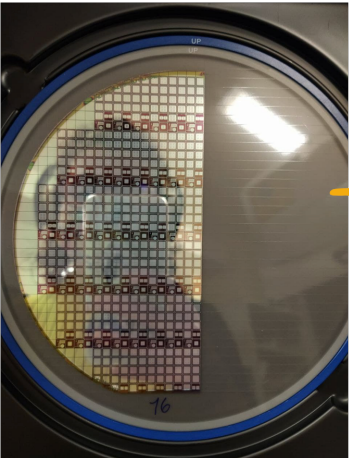
- 1060 nm picosecond laser with $\sim 10 \mu\text{m}$ spot
- Charge vs laser position fitted with S-curve: convolution of gain layer step function and laser gaussian beam profile
- No-gain distance is defined as the distance between the points at 50% of the two S-curves maximum

1D scan along the optical window



ETL design

Final sensor:
16x16 array
1.3x1.3 mm² pixels



R&D productions

